

Jan 20 04 10:42a

Jacqueline J Garner

972-278-9775

P. 1

To: Technology Center 2800
Facsimile Number: 703-872-9306

Total Pages Sent 10

RECEIVED
CENTRAL FAX CENTER

From: Jacqueline J. Garner
Texas Instruments Incorporated
Facsimile: 972-917-4418
Phone: 214-532-9348

JAN 20 2004

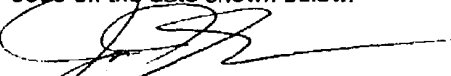
OFFICIAL

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 10/023,825 Confirmation No. 8239
Applicant : Jorge A. Kittl et al.
Filed : 12/19/2001
TC/A.U. : 2829
Examiner : Russell M. Kobert
Docket No. : TI-23892
Customer No. : 23494
Title : METHOD TO IMPROVE SILICIDE FORMATION ON
POLYSILICON

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by
facsimile to the U.S. Patent and Trademark Office at 703-872-
9306 on the date shown below:


Jacqueline J. Garner, Reg. No. 36,144

January 20, 2004
Date

FACSIMILE COVER SHEET

<input checked="" type="checkbox"/> FACSIMILE COVER SHEET	<input checked="" type="checkbox"/> AMENDMENT (6 Pages)
<input type="checkbox"/> NEW APPLICATION	<input checked="" type="checkbox"/> EOT 1mth (3 Pages)
<input type="checkbox"/> DECLARATION (# Pages)	<input type="checkbox"/> NOTICE OF APPEAL (# Pages)
<input type="checkbox"/> ASSIGNMENT (# Pages)	<input type="checkbox"/> APPEAL (# Pages)
<input type="checkbox"/> FORMAL DRAWINGS	<input type="checkbox"/> ISSUE FEE (# Pages)
<input type="checkbox"/> INFORMAL DRAWINGS	<input type="checkbox"/> REPLY BRIEF (IN TRIPLICATE) (# Pages)
<input type="checkbox"/> CONTINUATION APP'N (# Pages)	
<input type="checkbox"/> DIVISIONAL APP'N	

NAME OF INVENTOR(S): Kittl		RECEIPT DATE & SERIAL NO.:	
TITLE OF INVENTION: Method to Improve Silicide Formation . . .		Serial No.: 10/023,825	
TI FILE NO.: TI-23892		Filing Date: 12/19/2001	
DEPOSIT ACCT. NO.: 20-0668		Conf. No. 8239	
FAXED: 1/20/2004			
DUE: 12/17/2003			
ATTY/SECY: JJG			

This facsimile is intended only for the use of the address named and contains legally privileged and/or confidential information. If you are not the intended recipient of this telecopy, you are hereby notified that any dissemination, distribution, copying or use of this communication is strictly prohibited. Applicable privileges are not waived by virtue of the document having been transmitted by Facsimile. Any misdirected facsimiles should be returned to the sender by mail at the address indicated on this cover sheet.

Texas Instruments Incorporated
PO Box 655474, M/S 3999
Dallas, TX 75074

RECEIVED
CENTRAL FAX CENTER

JAN 20 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

OFFICIAL

Appl. No. : 10/023,825
Applicant : Jorge A. Kittl et al.
Filed : 12/19/2001
TC/A.U. : 2829
Examiner : Russell M. Kobert

Confirmation No. 8239

Docket No. : TI-23892
Customer No. : 23494

Title : METHOD TO IMPROVE SILICIDE FORMATION ON
POLYSILICON

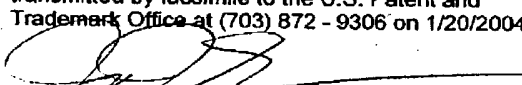
AMENDMENT UNDER 37 CFR 1.111

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being
transmitted by facsimile to the U.S. Patent and
Trademark Office at (703) 872 - 9306 on 1/20/2004.


Jacqueline J. Garner
Reg. No. 36,144

The following amendments and remarks are offered in response to the Examiner's Office Action dated 9/17/2003. They are respectfully submitted as a full and complete response to that Action.

Please amend the above-referenced application as follows:

Amendments to the ABSTRACT begin on page 2.

Amendments to the Claims are reflected in the listing of claims that begin on page 3 of this paper.

There are no **Amendments to the Drawings**.

The **Remarks** begin on page 4.